Floating-zone growth of K_x Fe_{2-y}Se₂ single crystals

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The discovery of superconductivity at temperatures above 30 K in $K_xFe_{2-y}Se_2$ compounds has attracted considerable attention [1]. The crystal structure of $K_xFe_{2-y}Se_2$ descends from the well-known ThCr₂Si₂ structure with vacancies at the Fe sites. It was soon found that magnetism and superconductivity coexist in $A_xFe_{2-y}Se_2$ (A = K, Rb, and Cs) [2-3]. Even in single crystals which show full shielding of an external magnetic field below the superconducting transition temperature (T_c), antiferromagnetic order is found below the Néel temperature (T_c), as high as 500 to 540 K, depending on the alkaline element T_c [3]. Moreover, the microstructure analysis on T_c see single crystals indicates a clear phase separation in the superconducting samples. Two phases in the form of parallel lamellae, namely iron-vacancy-ordered and -disordered phases, stack along the T_c axis of the crystal. Furthermore, the temperature dependence of single-crystal x-ray diffraction (XRD) in transmission mode reveals a minority non-magnetic phase with a weak T_c superstructure, in addition to the majority magnetic phase with a ThCr₂Si₂-type tetragonal lattice modulated by the T_c iron-vacancy ordering below 520 K. Therefore, the relation between superconductivity and iron-vacancy ordering structure remains a subject of debate.

These complex microstructures make it difficult to grow bulk superconducting $A_x Fe_{2-\nu} Se_2$ (A = K, Rb, and Cs) single crystals. Success in obtaining superconducting samples strongly depends on the ratios of the starting chemical components, particularly on the initial Fe content, as well as heating, cooling and growth rates. So far, different techniques such as flux growth and the Bridgman method have been used to grow A_xFe_{2-y}Se₂ (A=K, Rb, and Cs) single crystals [3] with typical procedure as follows: First, FeSe precursor was synthesized at 700 °C in an evacuated quartz tube. Then, FeSe precursor was ground into powder and mixed with K(Rb,Cs) at a ratio of K(Rb,Cs):Fe:Se=0.8:2:2. The mixtures were loaded into a double sealed quartz ampoule and then heated to 1030 °C and kept at this temperature for 2 h. A fast cooling rate of 6 °C/h was applied before turning off the furnace at 750 °C. However, the as-grown crystals obtained by these methods hardly showed 100% superconducting volume, mainly due to the inhomogeneity of the samples, since ordered or disordered vacancy phases could be randomly formed due to an uncontrolled thermal distribution of iron vacancies during growth under the described conditions. In this study, we report that superconducting $K_xFe_{2-\nu}Se_2$ single crystals can be reproducibly grown by the optical floating-zone (OFZ) technique. Single crystals of a large size and high quality and high superconducting volume fraction are achievable, offering sufficient material for future inelastic neutron-scattering experiments.

The raw materials for the preparation of a feed rod were K (99.95%), Fe (99.995%) and Se (99.999%). The feed rod was synthesized by the one-step solid-state reaction method. Elemental K, Fe and Se were weighed at a ratio of K:Fe:Se=0.8:2:2, and loaded into an alumina crucible. The elements were then sealed in a quartz tube under 400 mbar argon atmosphere and heated to 850 °C for 10 hours. Finally, the sintered $K_{0.8}$ Fe₂Se₂ mixture was ground into a powder. The powder was pressed into a feed rod with a cylindrical shape \sim 6–7 mm in diameter and \sim 70–80 mm in length with 600 bar of hydrostatic pressure. The feed rod was used to grow the crystal directly without the conventional process of sintering and pre-melting. A seed rod of 2 cm in length was cut from the feed rod.

The single crystal was obtained in an OFZ furnace with 4×300 W halogen lamps (Crystal System Inc. FZ-T-10000-H-III-VPR). The seed and feed shafts were rotated in opposite directions at rates of 20 rpm. The traveling rate was ~1.0 mm/h. Argon atmosphere was applied during the growth process at 8 bar. The composition of the crystals was determined by energy-dispersive X-ray spectroscopy

(EDX). X-ray diffraction analysis was performed on a Philips Xpert XRD diffractometer using Cu K α radiation λ =1.54056 Å. In-plane resistivity measurements were performed on a Physical Property Measurement System (PPMS, Quantum Design). DC magnetic susceptibility was measured using a SQUID-VSM magnetometer (Quantum Design). Neutron diffraction experiments were carried out to characterize the quality of as-grown single crystals at the IN3 instrument (ILL, Grenoble).

The floating zone method enables us to obtain large and high quality single crystals with a mass of up to ~ 1.8 g. A typical as-grown single-crystal ingot of $K_x Fe_{2-y} Se_2$ is shown in Fig. 1(a). As can be seen in Figs. 1(b) and (c), the cleaved termination of the \sim 1 cm ingot displays a large crystal grain with a shiny surface, while the remaining portion of the ingot appears to be non-crystalline with a bubblelike structure from the beginning towards the termination. This non-crystalline area has decomposed into K-poor K-Fe-Se, as determined by EDX. We also noticed thin filament-like deposits on the surface of the ingot throughout the entire growth process. This substance is pure Fe, according to EDX analysis. We have also observed that part of the grown ingot underwent decomposition during floating-zone growth. This feature strongly suggests that the $K_xFe_{2-y}Se_2$ single crystal is quite unstable. As the molten zone moves up, the already formed crystal continuously passes through a temperature zone, $T_{\rm d}$, where the crystal begins to decompose, as illustrated in Fig. 1(d). Thus, to avoid passing through the decomposition zone the lamp power was switched off towards the end of the growth process, resulting in non-decomposed crystal phase at the terminal part of the ingot. Using a thermocouple for direct measurement of the temperature distribution below the molten zone, we observed accurately that $T_{\rm m} \sim 889$, $T_{\rm i} \sim 784$ and $T_{\rm d} \sim 280$ °C, for the molten zone, solid-liquid interface and decomposition temperatures, as illustrated in Fig. 1(d), respectively. Therefore, as-grown crystals can only be obtained by quenching at between ~784 and ~280 °C. We also observed that a stable molten zone can be formed by optimizing the growth parameters of rotation and traveling velocity. In this study, the superconducting $K_x Fe_{2-y} Se_2$ single crystal could be grown at a traveling velocity of ~0.8 mm/h under 8 bar of argon pressure. The rotation of seed and feed rods is another important factor in producing a molten zone with a homogeneous composition distribution, which is a prerequisite condition for forming high quality single crystals.

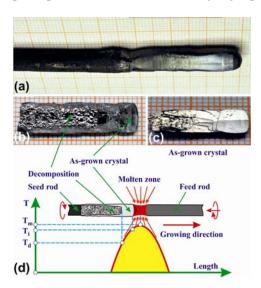


Figure 1: (a) As-grown $K_xFe_{2-y}Se_2$ single crystal ingot. (b) and (c) single crystals were cut off from the ingot (a) and cleaved along the growing direction. A shiny surface with (00l) orientation can only be observed at the termination of the ingot, whereas the remaining part of the ingot had decomposed. (d) The schematic drawing illustrates the growth process of the $K_xFe_{2-y}Se_2$ single crystals, which form between the solid-liquid interface temperature, T_i , and decomposition temperature, T_d , below which the crystals undergo a continuous decomposition during crystal traveling.

It is interesting to note that the inner diameter of ~ 25 mm of the grown ingot decomposed at ~ 280 °C, while an ingot ring width of about 1–1.5 mm remained in single crystal form, as shown in Fig. 1(b) and illustrated by Fig. 1(d), respectively. This phenomenon indicates that the decomposition is caused by a great thermal strain occurring in the inner crystal ingot. The fact is that after the crystal formed the latent heat of crystallization was hardly released along the radial direction which corresponds to

the robust (001) layers, perpendicular to the growth direction of the ingot. Therefore the compound decomposed to a K-poor K-Fe-Se.

The single crystals commonly represented an intergrowth of the iron-vacancy-ordered states and disordered states along the c-axis, which are characterized by slightly different lattice constants. Our XRD pattern was obtained by the (00l) reflections of the K_{0.80}Fe_{1.81}Se₂ single crystal, consistent with previous results [1], as shown in Fig. 2(a). Three shoulders besides the (008), (0010) and (0012) reflections can be discerned, as indicated by the asterisks. This second set of the (00l) reflections is related to the phase separation phenomenon. Single crystal powder XRD was performed to interpret the structure space group belonging to I4/m, related to the superstructure with the stronger reflections. The stronger reflections correspond to the lattice parameters of a = b = 8.688 and c = 14.128 Å that are commensurate with the superstructure reflections, indicating that they originate from the vacancy-ordered insulating phase. Therefore, the second phase with c = 14.134 Å (asterisks) must be attributed to the metallic phase without iron-vacancy ordering. The recent study of μ SR indicates that only a small volume (10%) of the sample is responsible for the superconducting phase. Therefore, we assume that the longer c-axis of 14.134 Å should be responsible for the superconducting phase with the iron-vacancy-disordered states, while the shorter one with a c-axis of 14.128 Å being responsible for the superstructure phase with the iron-vacancy-ordered states.

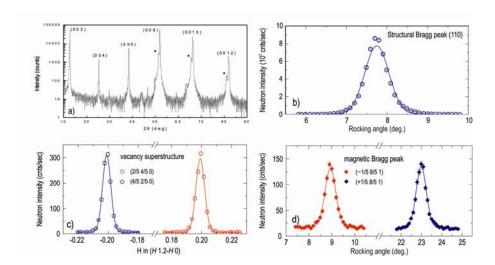


Figure 2: (a) XRD pattern of $K_{0.80}Fe_{1.81}Se_2$ single crystal. The shoulders located beside the main reflections are indicated by the asterisks, which correspond to the possible superconducting phase. (b) Neutron diffraction data showing Rocking curve of the (200) structural Bragg peak, indicating a resolution-limited mosaicity of the single crystal. (c) Superstructure Bragg reflections originating from the $\sqrt{5} \times \sqrt{5}$ iron-vacancy ordering. The two peaks correspond to the twin domains with opposite orientation of the vacancy superstructure with respect to the parent lattice directions. (d) Magnetic Bragg reflections from the two twin domains, measured at room temperature. The solid lines in all panels are Gaussian fits.

Now we turn to the description of magnetism in our samples, which we have characterized using single-crystal neutron diffraction. The data presented in Figs. 2(b-d) have been acquired on one piece of the as-grown sample with a mass of ~100 mg. The neutron wavevector was set to $k_i = 2.662 \text{ Å}^{-1}$. The sample was mounted in the (HK0) scattering plane and could be additionally tilted using the instrument's goniometers in order to reach the out-of-plane magnetic Bragg reflections. The resolution-limited rocking curve measured on the (200) structural Bragg peak, shown in Fig. 2(b), indicates that the mosaicity of the sample in the ab plane is of the order of ~0.5° or better.

As we already noted, the superconducting phase in the $K_xFe_{2-y}Se_2$ compound typically coexists with insulating vacancy-ordered regions that exhibit strong antiferromagnetic ordering at room

temperature. In Fig. 2(c), we show two superstructure reflections originating from the $\sqrt{5} \times \sqrt{5}$ Fevacancy ordering. The two peaks at (2/5 4/5 0) and (4/5 2/5 0) correspond to different twin domains with the counterclockwise and clockwise rotation of the vacancy superstructure about the *c*-axis with respect to the parent lattice directions in the *ab* plane, respectively. Their equal intensity indicates that the twins with both orientations are present in equal proportions in the sample. The presence of an antiferromagnetic order associated with this kind of vacancy superstructure, present at room temperature [2-3], is evidenced by Fig. 2(d). Here, we show the $(\pm 1/5 \text{ 8/5 1})$ magnetic Bragg peaks from the two twin domains, measured at T = 300 K. Due to the strong magnetic moment that, according to some reports, reaches 3.3 μ_B/Fe , their intensities are very strong despite the nearly twofold suppression due to the iron form-factor at this large $|\mathbf{Q}|$. If the correction for the magnetic form-factor is taken into account, the resulting magnetic Bragg intensity turns out to be comparable to that of the structural reflections in panel Fig. 2(c).

The temperature dependence of the in-plane resistivity ρ_{ab} of the K_{0.80}Fe_{1.81}Se₂ single crystal is shown in Fig. 3(a). A clear hump is observed around 220 K. This hump can be shifted by varying Fe content in K_xFe_{2-y}Se₂ single crystals, which has been interpreted in terms of the ordering process of the cation vacancies in the nonstoichiometric K_xFe_{2-y}Se₂. When considering the phase separation scenario, however, we suggest that the resistivity hump could result from the competition between the two electronic transport channels, i.e., insulating (iron vacancy ordering) and superconducting phases (iron vacancy disordering). Below 220 K, ρ_{ab} shows metallic behavior and the sample enters the superconducting state at $T_c = 31.7$ K. Consistent with the resistivity data, magnetization curves show the superconducting transition temperature at $T_c = 31.6$ K, leading to a near 100% expulsion of the external magnetic field in zero field cold below 5 K, as shown in Fig. 3 (b).

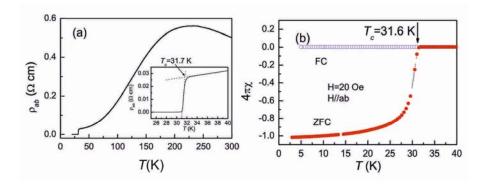


Figure 3: (a) Temperature dependence of the in-plane resistivity ρ_{ab} of a K_{0.80}Fe_{1.81}Se₂ single crystal. Inset shows a superconducting transition temperature at around $T_c = 31.7$ K. (b) Magnetization curves show the superconducting transition temperature at $T_c = 31.6$ K.

The optical floating zone technique can be successfully employed to grow the recently discovered $K_xFe_{2-y}Se_2$ superconducting single crystals. To avoid decomposition of the as-grown single crystals a quenching treatment is applied at the temperature range between 784 and 280 °C. Both metallic and superstructure phases are observed by the XRD reflections. Resistivity and magnetic measurements show a superconducting transition at $T_c \sim 32$ K.

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